



# GaN-HEMT 20W

# EGN26C020MK

High Voltage - High Power GaN-HEMT

### FEATURES

- High Voltage Operation :  $V_{DS}=50V$
- High Power : 43.5dBm (typ.) @  $P_{sat}$
- Power Gain : 18dB(typ.) @  $f=2.60GHz$
- Proven Reliability

### DESCRIPTION

SEDI's GaN-HEMT offers high efficiency, ease of matching, greater consistency and broad bandwidth for high power L-band amplifiers with 50V operation, and gives you higher gain.

This new product is ideally suited for use in 2.6GHz WiMAX design requirements as it offers high gain, long term reliability and ease of use.



### ABSOLUTE MAXIMUM RATINGS (Case Temperature $T_c=25^{\circ}C$ )

Item	Symbol	Condition	Rating	Unit
Operating-Voltage	$V_{DS}$		55	V
Drain-Source Voltage	$V_{DS}$	$V_{GS}=-8V$	160	V
Gate-Source Voltage	$V_{GS}$		-15	V
Total Power Dissipation	$P_t$		32.1	W
Storage Temperature	$T_{stg}$		-65 to +175	$^{\circ}C$
Channel Temperature	$T_{ch}$		250	$^{\circ}C$

### RECOMMENDED OPERATING CONDITION

Item	Symbol	Condition	Limit	Unit
DC Input Voltage	$V_{DS}$		$\leq 55$	V
Forward Gate Current	$I_{GF}$	$R_G=15\Omega$	$\leq 46$	mA
Reverse Gate Current	$I_{GR}$	$R_G=15\Omega$	$\geq -0.7$	mA
Channel Temperature	$T_{ch}$		$\leq 180$	$^{\circ}C$
Average Output Power	$P_{ave.}$		$\leq 42.0$	dBm

### ELECTRICAL CHARACTERISTICS (Case Temperature $T_c=25^{\circ}C$ )

Item	Symbol	Condition	Limit			Unit
			min.	Typ.	Max.	
Pinch-Off Voltage	$V_p$	$V_{DS}=50V$ $I_{DS}=5.2mA$	-1.0	-1.5	-2.0	V
Saturated Power	$P_{sat} *1$	$V_{DS}=50V$	42.5	43.5	-	dBm
Drain Efficiency	$\eta_d *2$	$I_{DS}(DC)=100mA$	10.5	12.5	-	%
Power Gain	$G_p *2$	$f=2.60GHz$	17.0	18.0	-	dB
Thermal Resistance	$R_{th}$	Channel to Case at 21W $P_{DC}$	-	6.0	7.0	$^{\circ}C/W$

\*1 : 10%-duty RF pulse (DC supply constant)

\*2 :  $P_{out} = 30dBm$ , CW



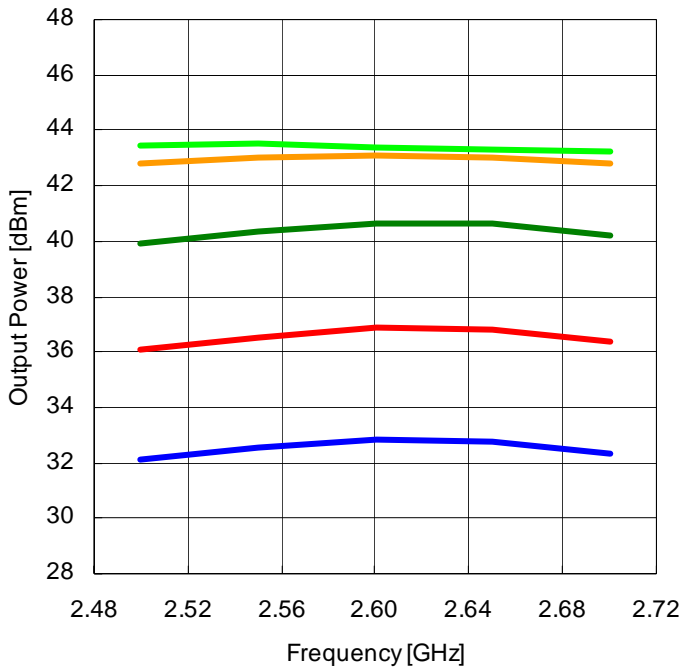
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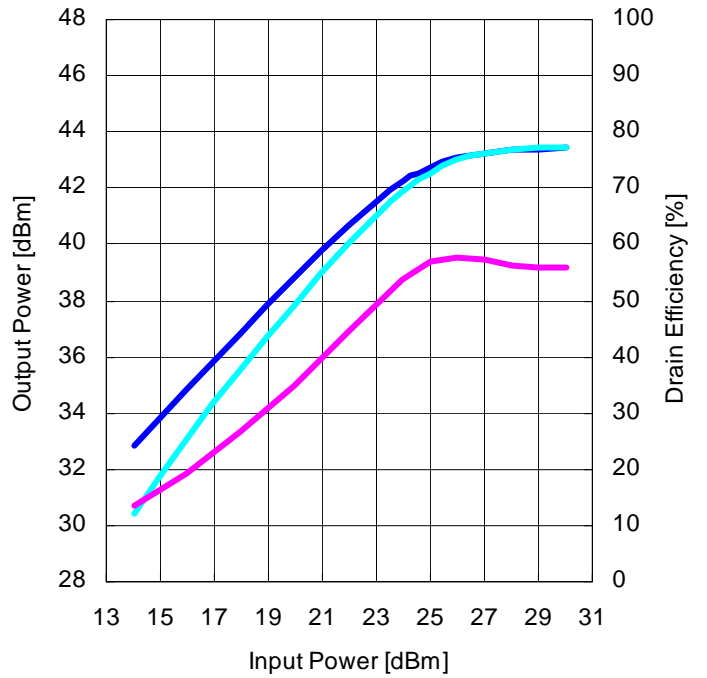
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RF characteristics @f=2.6GHz fine tuned

Output Power vs. Frequency  
V<sub>DS</sub>=50V, I<sub>DS(DC)</sub>=100mA



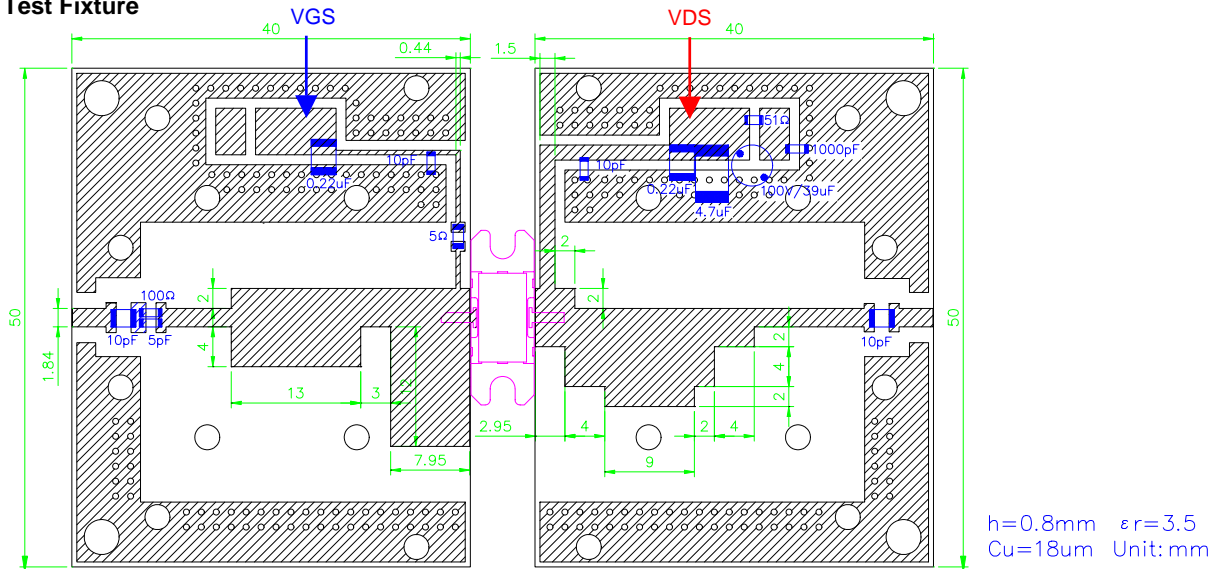
Output Power and Drain Efficiency vs. Input Power  
V<sub>DS</sub>=50V, I<sub>DS(DC)</sub>=100mA, f=2.60GHz



— Pin=16dBm    — Pin=20dBm    — Pin=24dBm  
— Pin=28dBm    — Pin=32dBm

— Pout (class AB)    — Pout (class B)    — Nd (class B)

### Test Fixture



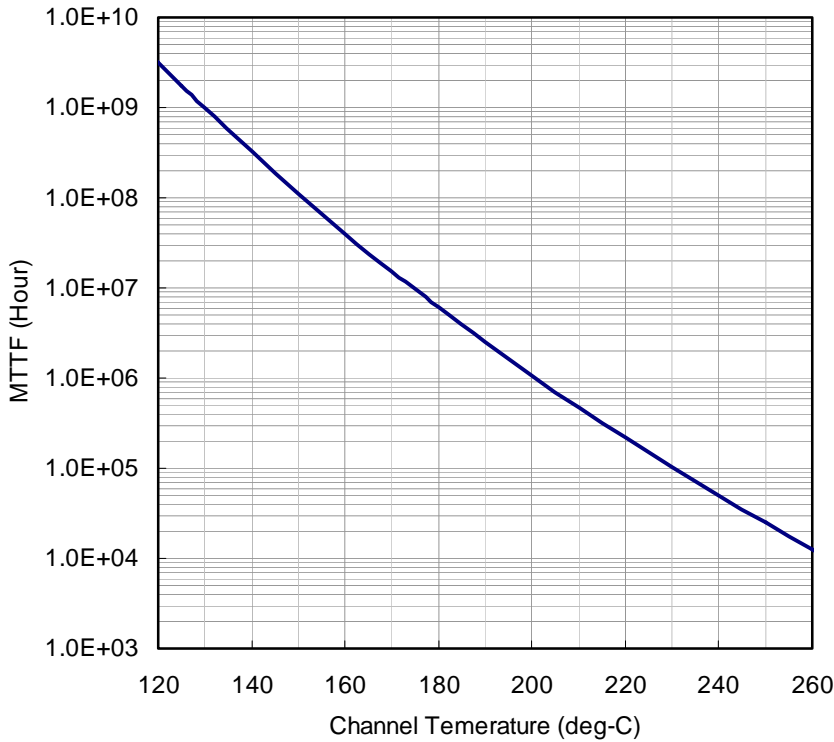


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MTTF Calculation  
- Estimated MTTF -



Ea=1.6eV  
Confidence Level=90%

Channel Temp (deg-C)	MTTF (Hours)
160	4.05 x 10 <sup>7</sup>
180	6.07 x 10 <sup>6</sup>
200	1.07 x 10 <sup>6</sup>

$$AF = \exp\left[-\frac{Ea}{k}\left(\frac{1}{T_{stress}} - \frac{1}{T_{use}}\right)\right]$$

$$MTTF_{use} = MTTF_{stress} * AF$$

Where;

AF: acceleration factor

Ea: activation energy (1.6 eV)

k: Boltzman's constant (8.62 x 10<sup>-5</sup> eV/K)

T<sub>stress</sub>: stress temperature (K)

T<sub>use</sub>: use temperature (K)

### ESD characteristic

Test Methodology	Class
Human Body Model (per JESD22-A114)	0
Machine Model (per JEI/ESD22-A115)	A



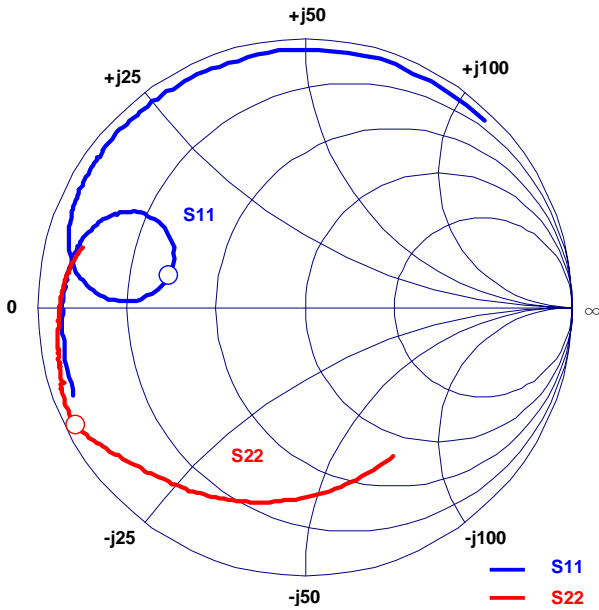
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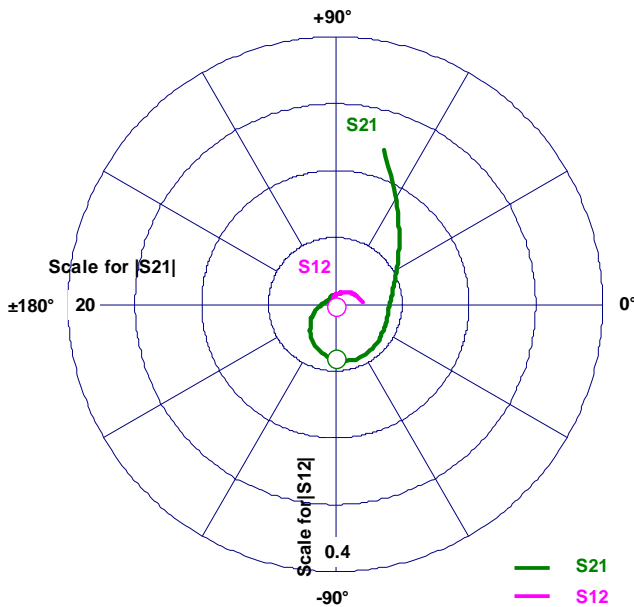
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- Reference DATA -

S-Parameters @V<sub>DS</sub>=50V, I<sub>DS(DC)</sub>=100mA, f=0.5 to 5.5GHz  
Z<sub>I</sub> = Z<sub>s</sub> = 50 ohm      Marker : 2.60GHz



Freq. GHz	S11		S21		S12		S22	
	MAG	ANG	MAG	ANG	MAG	ANG	MAG	ANG
0.50	0.93	-159.19	12.05	72.67	0.008	-1.13	0.64	-59.21
0.60	0.92	-165.19	10.07	65.04	0.008	-11.24	0.66	-67.21
0.70	0.91	-170.03	8.67	57.83	0.008	-8.32	0.67	-74.91
0.80	0.91	-173.90	7.54	51.35	0.007	-13.73	0.69	-82.34
0.90	0.91	-177.61	6.75	44.25	0.007	-17.97	0.71	-89.43
1.00	0.91	179.17	6.02	38.72	0.006	-20.17	0.72	-96.01
1.10	0.91	176.62	5.53	32.42	0.006	-18.84	0.74	-101.74
1.20	0.90	173.93	5.12	27.12	0.006	-22.89	0.76	-106.96
1.30	0.89	171.13	4.78	21.57	0.005	-17.63	0.77	-111.83
1.40	0.89	168.68	4.50	16.00	0.005	-13.48	0.79	-116.38
1.50	0.88	166.23	4.31	10.24	0.005	-6.36	0.80	-120.49
1.60	0.88	163.99	4.17	4.86	0.005	-11.42	0.82	-124.57
1.70	0.86	161.37	4.06	-1.20	0.005	-16.52	0.83	-128.11
1.80	0.84	159.01	4.00	-6.69	0.005	-6.58	0.84	-131.45
1.90	0.82	156.48	3.99	-13.77	0.005	-3.32	0.85	-134.45
2.00	0.79	154.01	4.01	-20.46	0.005	-7.37	0.87	-137.45
2.10	0.76	152.16	4.09	-28.21	0.006	-12.59	0.88	-139.70
2.20	0.71	149.99	4.18	-36.76	0.006	-15.90	0.90	-142.36
2.30	0.65	149.92	4.27	-47.32	0.006	-16.52	0.91	-144.90
2.40	0.58	151.61	4.39	-58.58	0.007	-25.56	0.93	-147.07
2.50	0.53	157.38	4.37	-72.92	0.009	-38.70	0.95	-149.76
2.60	0.52	167.15	4.20	-87.72	0.007	-52.32	0.96	-152.89
2.70	0.58	174.87	3.88	-102.47	0.008	-69.96	0.97	-155.81
2.80	0.65	177.98	3.42	-116.09	0.006	-80.21	0.97	-158.23
2.90	0.74	177.73	2.98	-128.93	0.006	-99.78	0.96	-160.60
3.00	0.80	175.15	2.53	-138.41	0.005	-119.97	0.96	-162.49
3.10	0.85	172.80	2.16	-147.75	0.004	-141.80	0.95	-164.16
3.20	0.88	170.45	1.85	-154.40	0.003	-149.33	0.95	-165.84
3.30	0.90	167.38	1.61	-161.06	0.003	-148.32	0.94	-167.06
3.40	0.92	164.78	1.40	-167.06	0.002	170.04	0.94	-168.50
3.50	0.93	162.21	1.25	-171.97	0.004	154.83	0.94	-169.83
3.60	0.94	160.05	1.10	-175.94	0.004	152.92	0.94	-170.97
3.70	0.94	157.64	1.00	-179.26	0.005	138.47	0.94	-172.18
3.80	0.95	155.78	0.90	176.14	0.006	132.27	0.93	-173.24
3.90	0.95	153.40	0.84	171.68	0.007	123.62	0.93	-174.53
4.00	0.95	151.26	0.77	168.54	0.007	123.57	0.93	-175.56
4.10	0.95	148.89	0.73	164.98	0.008	110.61	0.92	-176.60
4.20	0.96	146.32	0.68	161.09	0.009	107.64	0.92	-177.84
4.30	0.95	143.92	0.66	157.85	0.011	96.89	0.92	-178.79
4.40	0.95	140.71	0.63	154.07	0.012	94.01	0.92	-179.95
4.50	0.96	137.18	0.61	150.11	0.013	88.39	0.92	178.92
4.60	0.96	133.23	0.61	146.45	0.015	82.84	0.92	177.68
4.70	0.95	129.21	0.60	142.40	0.016	74.42	0.91	176.35
4.80	0.95	124.24	0.60	137.31	0.018	66.72	0.91	175.22
4.90	0.96	118.27	0.61	132.50	0.021	59.95	0.90	173.83
5.00	0.96	111.62	0.62	126.80	0.022	54.30	0.90	172.54
5.10	0.95	103.04	0.65	120.94	0.025	47.20	0.90	171.14
5.20	0.96	92.99	0.67	113.37	0.027	38.78	0.89	169.67
5.30	0.96	80.30	0.70	105.36	0.032	28.47	0.88	168.11
5.40	0.96	65.14	0.74	94.28	0.036	16.94	0.87	166.53
5.50	0.97	45.94	0.78	83.11	0.041	4.00	0.86	164.91





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## MK Package Outline Metal-Ceramic Hermetic Package

